

500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifierRev. 2 — 20 September 2010Product

Product data sheet

#### 1. **Product profile**

### **1.1 General description**

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier in common cathode configuration with an integrated guard ring for stress protection, encapsulated in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

### 1.2 Features and benefits

- Average forward current:  $I_{F(AV)} \le 0.5 A$  AEC-Q101 qualified
- Reverse voltage:  $V_R \le 40 V$
- Low forward voltage

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)

### 1.4 Quick reference data

#### Table 1. Quick reference data

 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

·						
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per diode						
I <sub>F(AV)</sub> average forward current	average forward current	square wave; $\delta = 0.5$ ; f = 20 kHz				
		$T_{amb} \le 85 \ ^{\circ}C$	<u>[1]</u> _	-	0.5	А
		$T_{sp} \le 130 \ ^\circ C$	-	-	0.5	А
V <sub>R</sub>	reverse voltage		-	-	40	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.5 A	-	410	470	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 40 V	-	27	100	μA

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.

- Small SMD plastic package
- Reverse polarity protection
- High-speed switching
- Low power consumption applications

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#### **Pinning information** 2.

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)	—-	
2	anode (diode 2)		3
3	common cathode	1 2	
			006aaa438

3. **Ordering information** 

Table 3. Ordering	g information		
Type number	Package		
	Name	Description	Version
PMEG4005CT	-	plastic surface-mounted package; 3 leads	SOT23

#### Marking 4.

Type number	Marking code <sup>[1]</sup>	
PMEG4005CT	PA*	

- -: made in Hong Kong \* = p: made in Hong Kong
- \* = t: made in Malaysia
- \* = W: made in China

#### **Limiting values** 5.

#### Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C	-	40	V
I <sub>F(AV)</sub>	average forward current	square wave; $\delta$ = 0.5; f = 20 kHz			
		$T_{amb} \le 85 \ ^{\circ}C$	<u>[1]</u> -	0.5	А
		$T_{sp} \le 130 \ ^{\circ}C$	-	0.5	А
I <sub>FRM</sub>	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	3.9	A
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8 ms	<u>[2]</u> _	10	A

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#### Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device; o	ne diode loaded				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[3]</u> _	330	mW
			<u>[4]</u> _	400	mW
			<u>[1]</u> -	460	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[2]  $T_j = 25 \,^{\circ}C$  prior to surge.

- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

### 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	; one diode loaded					
R <sub>th(j-a)</sub>	thermal resistance from	in free air	<u>[1]</u>			
junction to ambient	ambient	[2] _	-	375	K/W	
		[3]	-	310	K/W	
			<u>[4]</u>	-	270	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		<u>[5]</u> _	-	60	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

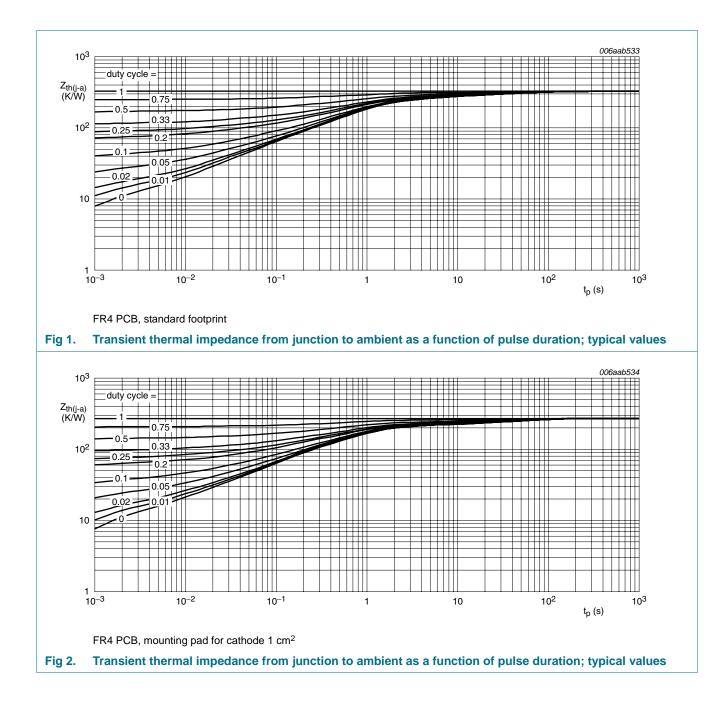
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[5] Soldering point of cathode tab.

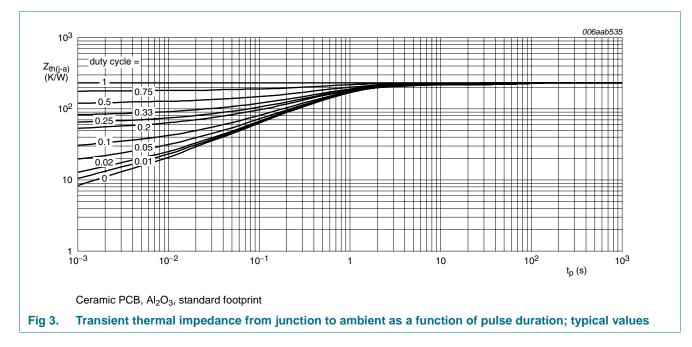
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# PMEG4005CT

### 500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifier



## 7. Characteristics

Table 7.Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V <sub>F</sub>	forward voltage	$I_{\rm F} = 0.1  {\rm mA}$	-	95	130	mV
	I <sub>F</sub> = 1 mA	-	155	210	mV	
	I <sub>F</sub> = 10 mA	-	220	270	mV	
		I <sub>F</sub> = 100 mA	-	295	350	mV
		I <sub>F</sub> = 500 mA	-	410	470	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	7	20	μΑ
		V <sub>R</sub> = 40 V	-	27	100	μΑ
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz	-	43	50	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> _	13	-	ns

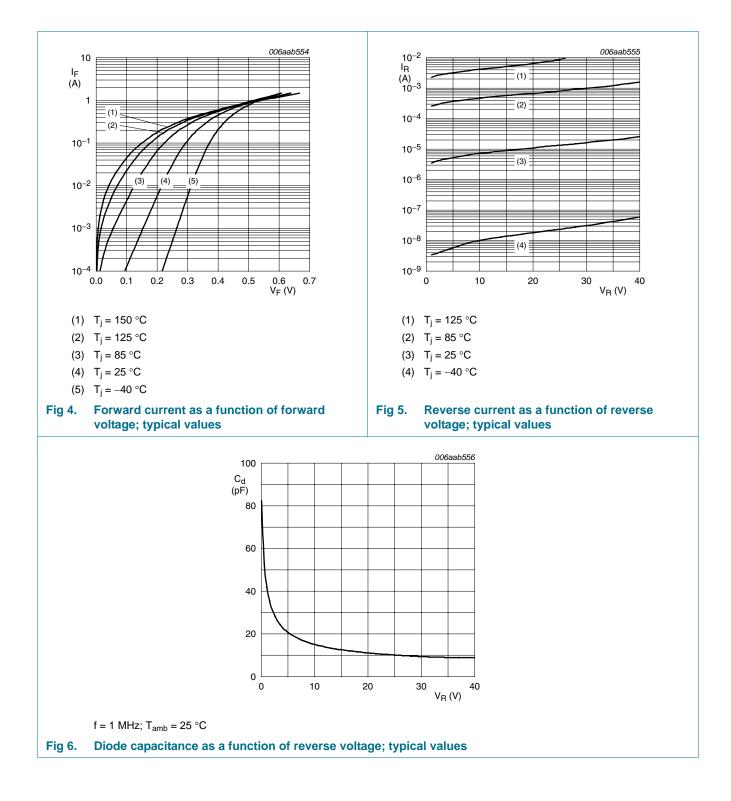
 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

[1] When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega;$  measured at  $I_R$  = 1 mA.

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# PMEG4005CT

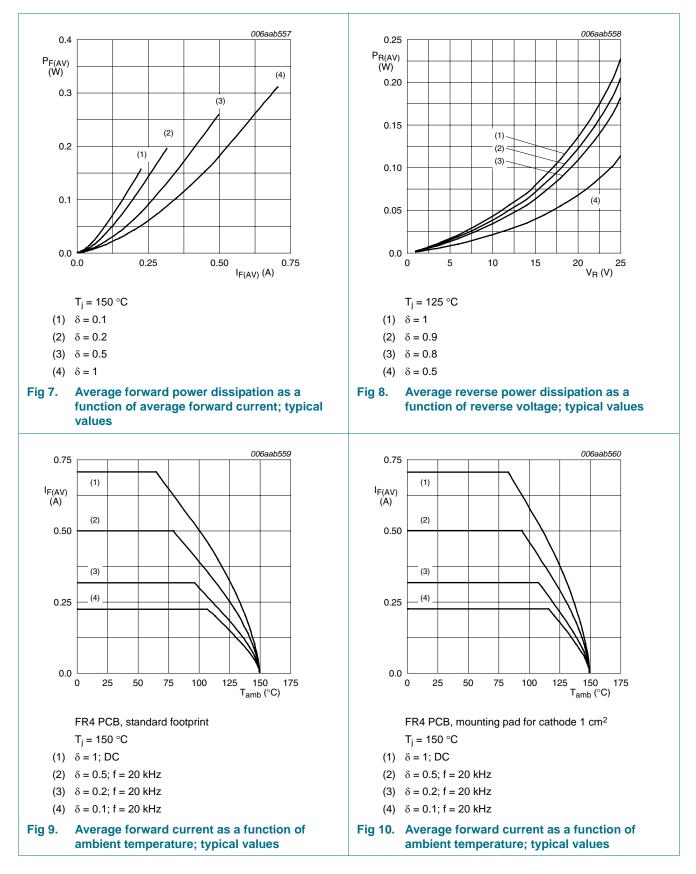
#### 500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifier



PMEG4005CT Product data sheet

# PMEG4005CT

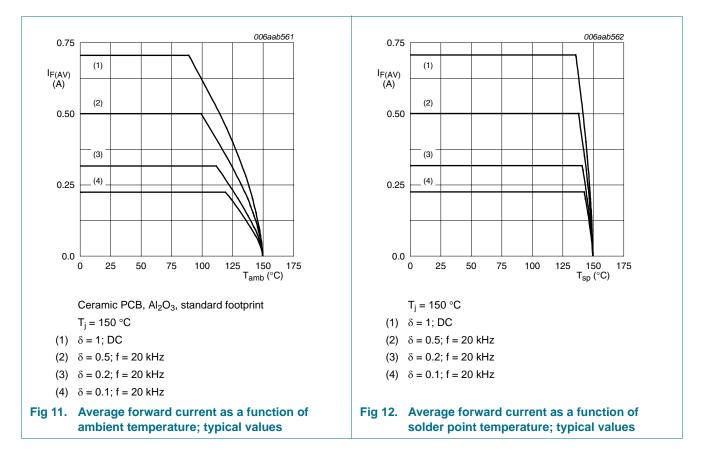
#### 500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifier



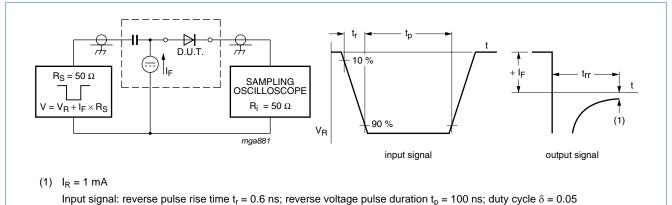
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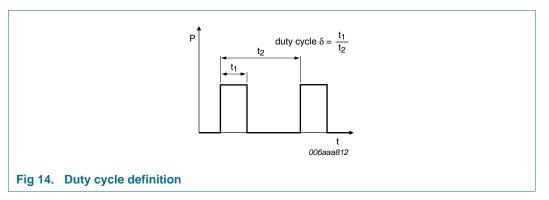
## 8. Test information



Oscilloscope: rise time  $t_r = 0.35$  ns

Fig 13. Reverse recovery time test circuit and waveforms

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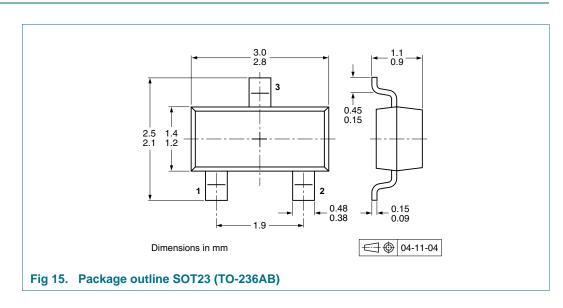
The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,

 $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



### **10. Packing information**

#### Table 8. Packing methods

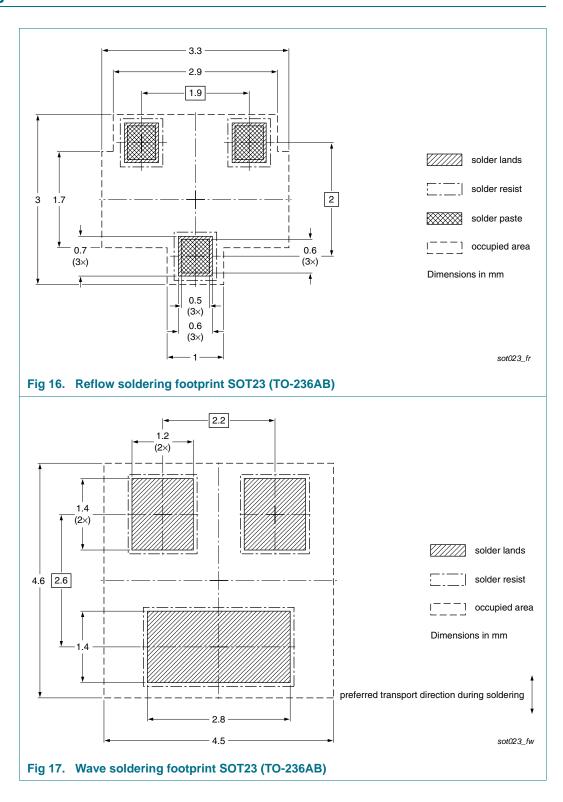
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	g quantity
			3000	10000
PMEG4005CT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

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[1] For further information and the availability of packing methods, see <u>Section 14</u>.

### 11. Soldering



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## **12. Revision history**

Table 9. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4005CT v.2	20100920	Product data sheet	-	PMEG4005CT_1
Modifications:	<ul> <li>Table 2 "Pin</li> </ul>	ning": Graphic symbol am	ended	
	Section 13 '	<u>'Legal information</u> ": update	ed	
PMEG4005CT_1	20090605	Product data sheet	-	-

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## 13. Legal information

### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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